

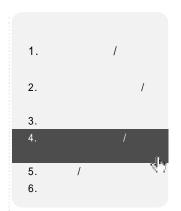
I

#### **Electronic Components**

本 記事 日本 CQ出版社가 發行 「トランジスタ技術」誌(2001年 4月號) 著作權 協定 依據 提供 資料

# 저항·코일·콘덴서의 모든 것 (4)

, , . 가 가 가 가



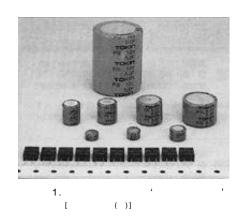
0.01~2,000F의 대용량이며 대전류 방전도 가능

## 전기 이중층 콘덴서

桑田 和彦

, (二重層) ( 1) , , ,

1. , , 가





60

### **Electronic Components**

2 , LED

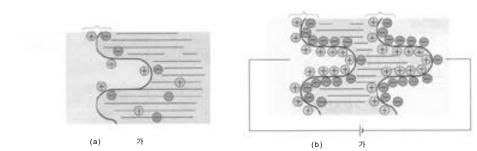
(+) (-) 7h .

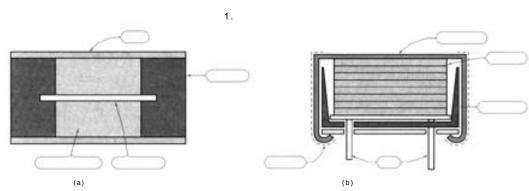
. 가 .

. 3.

1,000m²/g , (希) .

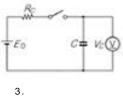
2. 4. (1) 가





가 24 24 (定) 3) 30 가 C[F] , :  $V_c = 0.632E_0$ 가 [ ], R<sub>c</sub> : 가 , 가 60 100 [ ] (2)  $T_b[sec]$  $T_b = \frac{C(V_0 - V_1 - V_{drop})}{I}$  .....(2) (低) , C : [F], V<sub>0</sub> : (3) [V],  $V_{drop}$ :  $[V], V_1$ : [V], I: [A], ( )]

	[F]	[V]	
	0.1 0.3	2.5 30	
	0.01 10	2.5 18	VTR, , , FAX,
	10 100	2.5 3.5	LED ,
45	0.1 0.33	1.6 5	
+ -	100 2,000	2.4 14	,



2002 · 2 61



### **Electronic Components**

T♭가

 $V_{drop} = R_i I$  ······(3)

drop ,

, 70% 가 6 7

가

. 6

FYD0H145Z(1.4F) +55

10 70%

1. , ,

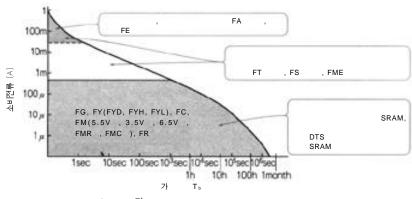
가 ,

가 .

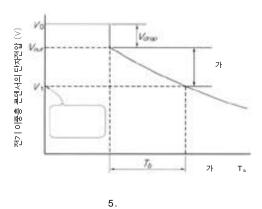
가

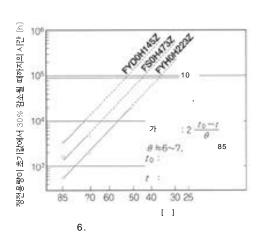
-25 +70 , -40 가 +85

.



4. 가



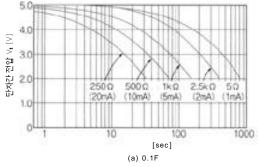


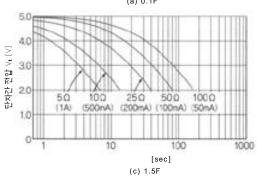
Ο.

2. , E : [V], R : [], 7 5.5V, 1F  $R_s$ : [ ] 3. 가 가 가 7 가 가 . 가 가 가  $R_{\text{s}}$  $I_{\text{C(peak)}}[A]$ 4. 16 : 5.5V, 1F : 1 단자간 전압 ¼ (∀) 전전용량 변화**율** [%] 내부 온도 (오) 8 8 6 **충**전전류 Ic (A) +25 [sec] +25 -25 +70 7. 8. FG1C107Z 151/ 100 F (a) (b) 2. ( 15V100F (c) , ( )] [ 10.



#### **Electronic Components**





9.

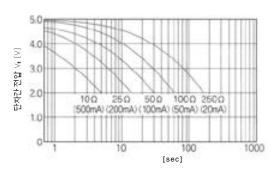
•

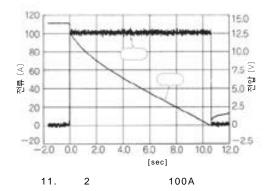
5. 0.1F, 0.47F 1.5F

.

9

1. : 1μA 100mA, 0.01 1F 10(a) . 가 가 OA





.

2. : 100m 1A, 1 100F 10(b)

, 10(c) (發電) LED

3. : 10 100A, 100 2,000F

15V 100F( 2)

(1) (株)ト - キン, ス - パ - キャパシタ使用ガイド, Vol.05.

本 記事 日本 CQ出版社가 發行 「トランジスタ技術」誌(2001年 4月號) 著作權 協定 依據

### 계측회로/전력회로/고주파회로로 사용

# 의 선정방법 및 사용방법 增田 幸夫/瀬川 毅/伊勢蝦 鶴蔵

가

가

가

가

가

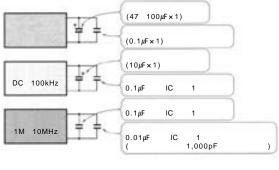
, IC

가 가 가 IC 가 가 가 2. 3 DVM IC ICL7106/7107 (1)  $C_{REF}$  -AZ( (trough) ΑZ OP (2) C<sub>AZ</sub> -가  $C_{\text{\tiny REF}}$ 가 가 (理想)  $(47 \ 100 \mu F \times 1)$ 

0.01μF

0.1μF

1.





### **Electronic Components**

(3) C<sub>INT</sub> -

.

. A-D

1/2,000

가 .

3.

4 2 LPF .

· 가 ,

E12

.

4. 5 1 HPF dB/oct. 가 .

7\ .  $C = 0.1\mu F, R = 10k\Omega$  CR

50/60Hz -10dB

. <増田 幸夫>

3. A-D

1. 가 RCL

( 6)

. 가 , 가

. 가 RCL

가 .

ESR( 가 ), ESL( 가 ) . ESR ESL

•

2.

66

(1)

1A 가

,

(2)

가 . ,

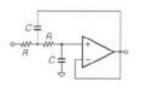
> OS >

가 . 가

, ESR

가

(3) 100V



4. RC



.

(4)

2. (

2)

(5)

,

3. ( 3)

.

· 가 (箔)

ESR . 3kV

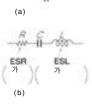
.

1.

1. ( 1)

4.

(1k 3kV )가 .



6.

	r	
		URL
( )	81-72-870-6310	www.secc.co.jp/
( )	81-262-47-4545	( )
( )	81-3-3775-9111	www.soshin.co.jp/
TDK( )	81-3-5201-7226	www.tdk.co.jp/tjfx01
( )	81-75-231-8461	www.nichicon.co.jp/
( )	81-3-5436-7711	www.chemi-con.co.jp/
( )	81-3-3442-8151	www.nissei-denki.co.jp/
( )	81-3-3798-9628	www.ic.nec.co.jp/compo/cap/
( )	81-6-6968-7171	www.maco.panasonic.co.jp/eccd/
( )	81-6-6332-0871	www.ncc-matsuo.co.jp/
( )	81-75-951-9111	www.murata.co.jp/



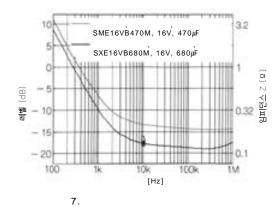


2.





### **Electronic Components**



.

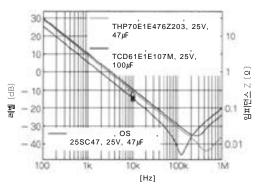
5. 'OS' ESR, ESL,

1.

가 , , (燒損) . . . 가

70% .

. 가



8. OS

,

2. 가 · · · · ·

가 . 가

3. 가 가

· · ·

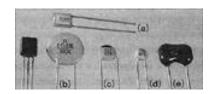
2001 11 ' · · · - - - 9

1. RCL . (trough) 가 ESR ESR 가 2. [Hz] 9. 7 가 . ESR -18dB ESR , 120m . ESR . RCL 가 가 10 3. OS 8 1. ESR -30dB 2 32m ESR ESR CH SL 2) 가 4. -40dB ( 3) (10m) . , ESR 가 . (積 重) 5. 9  $0.33\mu F$  1 M Hz . 4.7μF 10μF ' V ESR . ESR -40dB(10m ' 가 ) (4) . VHF

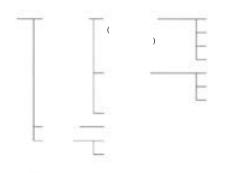
2002 · 2 69



### **Electronic Components**



(0.01μF 50V), (0.01μF 50V), [(a) (c) (e) , (b) B , (d)



10.

2. ( ) . ESR

( 5)

3.

가 455kHz

1M 4MHz

가 6

	2.		
	[( )	, GRM39 ]	
	[ppm/ ]	[ ]	50V [pF]
СН	0 ± 60		
Cl	0 ± 120	-55 +125	0.5 680
СК	0 ± 250		
PH	-150 ± 60		0 400
PJ	-150 ± 120		3 160
RH	-220 ± 60		
RJ	-220 ± 120		3 180
SH	-330 ± 60	-25 +85	
SJ	-330 ± 120		3 220
TH	-470 ± 60		
TJ	-470 ± 120		3 470
UJ	-750 ± 120		3 750
SL	+350 -1,000	+20 +85	62 750

(a)

С	±0.25pF	10pF
D	± 0.5pF	ТОРТ
J	± 5%	
К	± 10%	
М	± 20%	ТОРР
Z	+80%, -20%	

(b)

4.

5)

가

5. 가

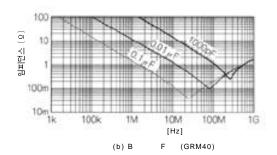
6

3 가

10

1.

[O] 100m 100M 1G 6G [Hz] (a) CH (GRM40)



11.

3.

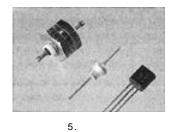
GRM ]
GRM

				[F]		
	[%]	[ ]	[ ]	1608	2012	3216
В	± 10	-25 +85	-25 +85	330p 0.0022 µ	330p 0.022 µ	0.082 μ 0.15 μ
R	± 15	-55 +125	-55 +125	330p 0.0022 µ	330p 0.022 µ	0.082 μ 0.15 μ
F	+30, -80	-25 +85	-25 +85	0.01μ 0.015μ	0.01 µ 0.068 µ	0.01μ 0.22μ
Y5V	+ 22, -82	-30 +85	-30 +85	-	-	-

4. [( ) ]

		[F]					
		50V	100V	200V	300V	500V	[mW]
GRH110	1414	0.5p 100p	-		-	-	120
GRH111	2828	750p 1,000p	510p 680p	220p 470p	110p 200p	0.5p 100p	245

(1) : CH(+25 +125 ), :-55 +125 (2) 20



5.

[( )]

		[pF]		
		100V	500V	
2012	UC12	0.5 43	-	
3225	UC23	43.5 430	0.5 150	
4532	UC34	240 820	91.5 470	
5750	UC55	820 2,000	470 1,200	

6.

-40 +85 50V, 100V

[ ( ), YX ]

50V, 100V ±5%(J), ±10%(K) 30G 0.001 μ 0.47μF

•

. 13

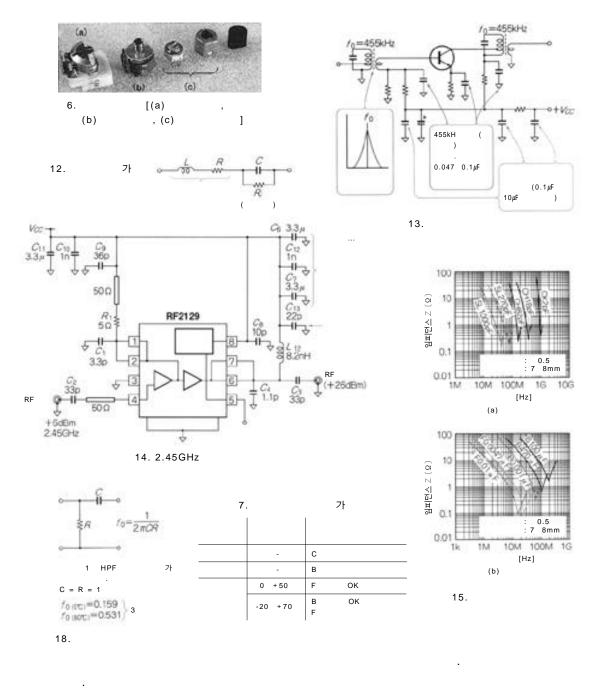
가

. LC ( ) 2.

. 가



### **Electronic Components**



.

정전용량 변화율 [%] 8 8 8 8 0 40 60 80 100 120 17. (50V 16. LC 가 가 정전용량 변화율 [%] 50V@1kHz ESL ESL 가 )가 EMC 3 30 [V] 19. 3. 16 17 . F DC 가 0V 2 가 -70% . 가 . LC 80 , L 18 가 가 가 7 (2) -300ppm/ 가 가 +300ppm/ . DC 60%가 가 19 B 15%, F 4. 20V

(1)

2002 · 2 73